

Automotive NJG1187AKGC-A GNSS High Gain Low Noise Amplifier

FEATURES

- AEC-Q100 grade 2 qualified
- Supply voltage 3.3 V typ.
- Low current consumption 8 mA typ.
- High gain
 34 dB typ. @ L1 band
 37 dB typ. @ L2/5 band
 36 dB typ. @ L6 band
- Low noise figure
 0.60 dB typ. @ L1 band
 0.65 dB typ. @ L2/5/6 band
- Package with wettable flank
 1.6 x 1.6 x 0.78 mm typ., pin pitch 0.5 mm
- RoHS compliant and Halogen Free, MSL1

APPLICATIONS

- GNSS receive application for automotive
- Active antenna, dashboard camera, and navigation
- GNSS module

GENERAL DESCRIPTION

The NJG1187AKGC-A is a high gain low noise amplifier (LNA) designed for GNSS applications. The NJG1187AKGC-A is available to be tuning for L1 (1.5 GHz) or L2/5/6 (1.1 to 1.2 GHz) bands by changing only value of external parts.

Its wide operating temperature range from -40 to +105°C is suitable for automotive applications. Integrated ESD protection device on each port

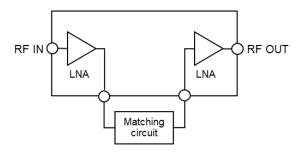
achieves excellent ESD robustness. ESON6-GC package with wettable flank structure is

adopted for Automated Optical Inspection (AOI) of solder joint.

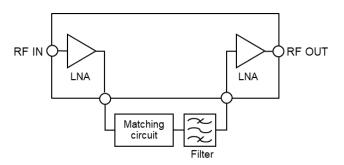


ESON6-GC (1.6 x 1.6 x 0.78 mm)

BLOCK DIAGRAM



APPLICATION EXAMPLE





PRODUCT NAME INFORMATION

NJG1187A KGC -A (TE3)

Description of configuration

Suffix	Parameter	Description
KGC	Package code	Indicating the package. Refer to the order information for detail.
-A	Grade	Indicating the quality grade.
(TE3)	Packing	Refer to the packing specifications for detail.

Grade

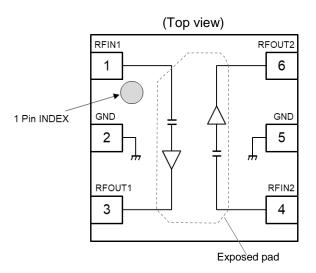
Suffix	Applications	Operating Temperature Range	Test Temperature
-A	Chassis, Body control and In-vehicle	−40°C to 105°C	25°C, 105°C

ORDER INFORMATION

PRODUCT NAME	PACKAGE	RoHS	HALOGEN- FREE	PLATING COMPOSITION	MARKING	WEIGHT (mg)	Quantity per Reel (pcs)
NJG1187AKGC-A	ESON6-GC	Yes	Yes	SnBi	1187A A	5.4	3,000



■ PIN DESCRIPTIONS



ESON6-GC Pin Configuration

Pin No.	Pin Name	Description
1	RFIN1	RF input terminal to 1st amp.
2	GND	Ground terminal
3	RFOUT1	RF output from 1st amp. and voltage supply terminal
4	RFIN2	RF input terminal to 2nd amp.
5	GND	Ground terminal
6	RFOUT2	RF output from 2nd amp. and voltage supply terminal
Exposed pad	-	Ground terminal

Please refer to "APPLICATION CIRCUIT" for details.



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Automotive NJG1187AKGC-A

ABSOLUTE MAXIMUM RATINGS

		$I_a = +25^{\circ}C, 2$	$L_{\rm s} = Z_{\rm l} = 50 \ \Omega$
Parameter	Symbol	Ratings	Unit
Supply voltage	V _{DD}	5.0	V
Input power	PIN ⁽¹⁾	+15	dBm
Power dissipation	P _D ⁽²⁾	1100	mW
Operating temperature	T _{opr}	-40 to +105	°C
Storage temperature	T _{stg}	-55 to +150	°C

(1): V_{DD} = 3.3 V

(2): 4-layer FR4 PCB with through-hole (101.5 x 114.5 mm), $T_j = 150^{\circ}C$

ABSOLUTE MAXIMUM RATINGS

Electronic and mechanical stress momentarily exceeded absolute maximum ratings may cause permanent damage and may degrade the lifetime and safety for both device and system using the device in the field. The functional operation at or over these absolute maximum ratings is not assured.

^{*1} Please calculate the power consumption of the IC from the operating conditions, and calculate the junction temperature with the thermal resistance.

Please refer to "Thermal characteristics" for the thermal resistance under our measurement board conditions.

THERMAL CHARACTERISTICS

Parameter	Measurement Result
Thermal Resistance (θja)	θja = 116°C/W
Thermal Characterization Parameter (wjt)	ψjt = 43°C/W

θja: Junction-to-Ambient Thermal Resistance

Ψjt: Junction-to-Top Thermal Characterization Parameter

■ ELECTROSTATIC DISCHARGE (ESD) PROTECTION VOLTAGE

Deremeter	Conditions	Pin No.	Pin Name	Protection Voltage		
Parameter	Conditions	FIITNO.	FILLINALLE	Ground	I/O	
		1	RFIN1	±1750 V	±250 V	
		2	GND	COM.	-	
		3	RFOUT1	±2000 V	±1750 V	
HBM	HBM : C = 100 pF, R = 1.5 kΩ	4	RFIN2	±2000 V	±1750 V	
		5	GND	COM.	-	
		6	RFOUT2	±1500 V	±1500 V	

Parameter	Conditions	Protection Voltage
CDM	Direct CDM	±2000 V

ELECTROSTATIC DISCHARGE RATINGS

The electrostatic discharge test is done based on JESD47. In the HBM method, ESD is applied using the power supply pin and GND pin as reference pins.



■ RECOMMENDED OPERATING CONDITIONS

Parameter	Symbol	Ratings	Unit			
Supply voltage	V _{DD}	1.5 to 3.7	V			
Ambient Operating Temperature	Ta	-40 to 105	°C			
RECOMMENDED OPERATING CONDITIONS						
All of electronic equipment should be designed that the mounted semiconductor devices operate within the recommended operating conditions. The semiconductor devices cannot operate normally over the recommended operating conditions, even if when they are used over such conditions by momentary electronic noise or surge. And the semiconductor devices may receive serious damage when they continue to operate over the recommended operating conditions.						

■ ELECTRICAL CHARACTERISTICS 1 (DC)

		General conditions:	T _a = +25	°C, with a	applicatio	on circuit
Parameter	Symbol	Condition	MIN.	TYP.	MAX.	Unit
Supply voltage	Vdd		1.5	3.3	3.7	V
Operating current	IDD	RF OFF, V _{DD} = 3.3 V	-	8.0	13.0	mA

Electrical characteristics 2 (RF)

General conditions: V_{DD} = 3.3 V, f_{RF} = 1559 to 1610 MHz, T_a = +25°C, Z_s = Z_l = 50 Ω , with application circuit

Parameter	Symbol	Condition	MIN.	TYP.	MAX.	Unit
Small signal gain	Gain	f = 1575 MHz (L1 band) Exclude PCB, Connector Losses (0.15 dB)	29.0	34.0	-	dB
Noise figure	NF	f = 1575 MHz (L1 band) Exclude PCB, Connector Losses (0.08 dB)	-	0.60	1.15	dB
Isolation	ISL	f = 1575 MHz (L1 band)	45.0	52.0	-	dB
Output power at 1 dB gain compression point	P-1dB(OUT)	f = 1575 MHz (L1 band)	+7.0	+14.0	-	dBm
Output 3rd order intercept point	OIP3	f1= 1575 MHz, f2 = f1 + 1 MHz, P _{IN} = -42 dBm	+8.0	+16.0	-	dBm
RF IN return loss	RLi	f = 1575 MHz (L1 band)	5	10	-	dB
RF OUT return loss	RLo	f = 1575 MHz (L1 band)	7	18	-	dB



Automotive NJG1187AKGC-A

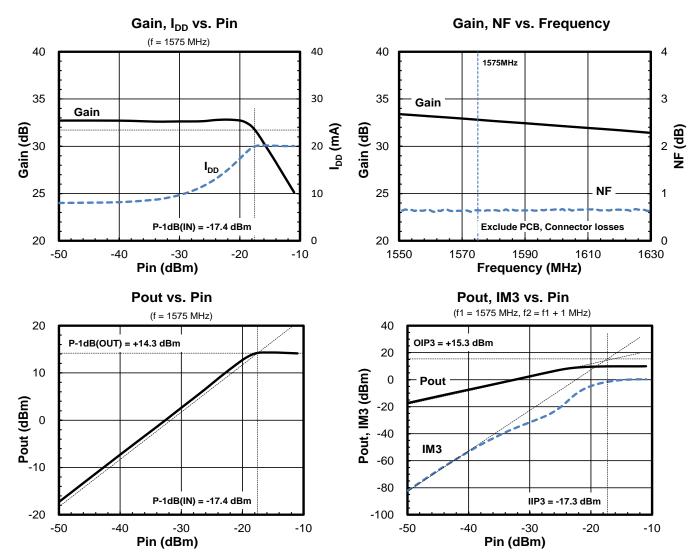
Electrical characteristics 3 (RF)

$ \begin{array}{ c c c c c c c c c c c c c c c c c c c$	General conditior	s: V _{DD} = 3.3 V,	$f_{RF} = 1164 \text{ to } 1300 \text{ MHz}, T_a = +25^{\circ}\text{C}, Z_s = Z_l = 1000 \text{ MHz}$	= 50 Ω, v	T	ication o	circuit	
$ \begin{array}{c c c c c c c c c c c c c c c c c c c $	Parameter	Symbol		MIN.	TYP.	MAX.	Unit	
$ \begin{array}{c c c c c c c c c c c c c c c c c c c $				33.0	37.0	_		
$ \begin{array}{c c c c c c c c c c c c c c c c c c c $				00.0	57.0		-	
$\frac{Exclude PCB, Conflector Dosses (0.10 dB)}{f = 1278 MHz (L5 band)} \frac{1}{31.0} \frac{36.0}{36.0} - \frac{1}{6}$ Noise figure $NF = \frac{1776 MHz (L5 band)}{F = 1277 MHz (L2 band)} \frac{1}{2000 CONnector Losses (0.05 dB)} \frac{1}{0.65} \frac{1.05}{1.05} dB$ $\frac{1}{F = 1277 MHz (L2 band)} \frac{1}{F = 1277 MHz (L2 band)} \frac{1}{1.05} \frac{1}{0.65} \frac{1.05}{1.05} dB$ $\frac{1}{F = 1277 MHz (L2 band)} \frac{1}{1.05} \frac{1}{1.$	Small signal gain	Gain		32.5	37.0	-	dB	
$\frac{Exclude PCB, Connector Losses (0.11 dB)}{f = 1176 MHz (L5 band)} \frac{31.0}{5.0} \frac{36.0}{5} \frac{-1}{1.05} \frac{1}{1.05} \frac{1}{$								
$ \begin{array}{c c c c c c c c c c c c c c c c c c c $				31.0	36.0	-		
$ \begin{array}{c c c c c c c c c c c c c c c c c c c $								
$ \begin{array}{c c c c c c c c c c c c c c c c c c c $				-	0.65	1.05		
$\frac{\text{Noise figure}}{\text{Noise figure}} = \frac{\text{Nr}}{\text{I}} = \frac{\text{Exclude PCB, Connector Losses (0.06 dB)}{\text{I}} = \frac{10.65}{1.05} $							-	
$ \begin{array}{ c c c c c c c c c c c c c c c c c c c$	Noise figure	NF		-	0.65	1.05	dB	
$ \begin{array}{ c c c c c c c c c c c c c c c c c c c$				-	0.65	1.05		
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$								
$ \begin{array}{c c c c c c c c c c c c c c c c c c c $			f = 1176 MHz (L5 band)	44.5	50.0	-		
$ \begin{array}{c c c c c c c c c c c c c c c c c c c $				44.5	50.0			
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	Isolation	ISL	f = 1227 MHz (L2 band)	44.5	50.0	-	aв	
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$			f = 1279 MHz (I.6 bond)	11 E	50 F			
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$				44.0	50.5	-		
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$			f – 1176 MHz (I 5 band)	+7.0	+13.0	_		
$ \begin{array}{c c c c c c c c c c c c c c c c c c c $				17.0	. 10.0			
Gain compression point Image: transformed structure		P-1dB(OUT)	f = 1227 MHz (I 2 band)	+7 0	+13.0	-	dBm	
Output 3rd order intercept point f1 = 1176 MHz, f2 = f1 + 1 MHz, PIN = -42 dBm +9.0 +19.0 - OUtput 3rd order intercept point OIP3 $f1 = 1227$ MHz, f2 = f1 + 1 MHz, PIN = -42 dBm +11.0 +19.0 - dBm RF IN return loss RLi $f = 1176$ MHz (L5 band) 4 15 - RF OUT return loss RLo $f = 1176$ MHz (L5 band) 6 12 - RF OUT return loss RLo $f = 1176$ MHz (L5 band) 7 12 - RF OUT return loss RLo $f = 1227$ MHz (L2 band) 7 15 - dB					10.0			
Output 3rd order intercept point $P_{IN} = -42 \text{ dBm}$ $+9.0$ $+19.0$ -1 OIP3 $f1 = 1227 \text{ MHz}, f2 = f1 + 1 \text{ MHz}, \\ P_{IN} = -42 \text{ dBm}$ $+11.0$ $+19.0$ $-$ RF IN return lossRLi $f = 1176 \text{ MHz}, f2 = f1 + 1 \text{ MHz}, \\ P_{IN} = -42 \text{ dBm}$ 12.5 $+18.0$ $ return loss$ RLi $f = 1176 \text{ MHz} (L5 \text{ band})$ 4 15 $ f = 1227 \text{ MHz} (L2 \text{ band})$ 5 15 $ dB$ $f = 1278 \text{ MHz} (L6 \text{ band})$ 6 12 $ f = 1176 \text{ MHz} (L5 \text{ band})$ 7 12 $ f = 1278 \text{ MHz} (L6 \text{ band})$ 7 12 $ f = 1278 \text{ MHz} (L2 \text{ band})$ 7 12 $ f = 1278 \text{ MHz} (L2 \text{ band})$ 7 12 $ f = 1227 \text{ MHz} (L2 \text{ band})$ 7 12 $ f = 1227 \text{ MHz} (L2 \text{ band})$ 7 15 $ dB$ $f = 1227 \text{ MHz} (L2 \text{ band})$ 7 15 $-$			f = 1278 MHz (L6 band)	+7.0	+13.0	-		
Output 3rd order intercept point OIP3 $P_{IN} = -42 \text{ dBm}$ f1 = 1227 MHz, f2 = f1 + 1 MHz, $P_{IN} = -42 \text{ dBm}$ +11.0 +19.0 - dBm RF IN return loss RLi f = 1176 MHz (L5 band) 4 15 - f = 1227 MHz (L2 band) 5 15 - dBm RF IN return loss RLi f = 1176 MHz (L5 band) 6 12 - f = 1278 MHz (L6 band) 6 12 - dBm RF OUT return loss RLo f = 1176 MHz (L5 band) 7 12 - d = 1227 MHz (L2 band) 7 15 - dB			f1 = 1176 MHz, f2 = f1 + 1 MHz,	.0.0	10.0			
intercept point $P_{IN} = -42 \text{ dBm}$ $+11.0$ $+19.0$ $ dBM$ f1 = 1278 MHz, f2 = f1 + 1 MHz, $P_{IN} = -42 \text{ dBm}$ 12.5 $+18.0$ $-$ RF IN return loss RLi $f = 1176 \text{ MHz} (L5 \text{ band})$ 4 15 $ f = 1227 \text{ MHz} (L2 \text{ band})$ 5 15 $ dB$ $f = 1278 \text{ MHz} (L6 \text{ band})$ 6 12 $ f = 1278 \text{ MHz} (L5 \text{ band})$ 7 12 $ f = 1278 \text{ MHz} (L5 \text{ band})$ 7 12 $ f = 1277 \text{ MHz} (L2 \text{ band})$ 7 15 $ dB$ $f = 1277 \text{ MHz} (L2 \text{ band})$ 7 15 $-$				+9.0	+19.0	-		
$\frac{P_{\text{IN}} = -42 \text{ dBm}}{f1 = 1278 \text{ MHz}, f2 = f1 + 1 \text{ MHz}, p_{\text{IN}} = -42 \text{ dBm}}$ $12.5 + 18.0 - 12$				±11 0	±10 0	_	dBm	
$\frac{P_{IN} = -42 \text{ dBm}}{f = 1176 \text{ MHz (L5 band)}} + \frac{12.5}{4} + \frac{18.0}{15} - \frac{12.5}{15} + \frac{18.0}{15} + \frac{18.0}{15} + \frac{1176 \text{ MHz (L5 band)}}{f = 1277 \text{ MHz (L5 band)}} + \frac{12.5}{5} + \frac{1176 \text{ MHz (L5 band)}}{15} + \frac{115}{15} - \frac{115}{15} + \frac{1176 \text{ MHz (L2 band)}}{15} + \frac{11278 \text{ MHz (L6 band)}}{15} + \frac{112}{15} + \frac{11278 \text{ MHz (L5 band)}}{15} + \frac{112}{15} + \frac{112}{15} + \frac{11278 \text{ MHz (L5 band)}}{15} + \frac{112}{15} +$	intercept point	011 0		±11.0	+13.0	_	ubm	
PIN = -42 dBm Image: second seco				12.5	+18.0	-		
RF IN return loss RLi $f = 1227 \text{ MHz} (L2 \text{ band})$ 5 15 - dB $f = 1278 \text{ MHz} (L6 \text{ band})$ 6 12 -			$P_{IN} = -42 \text{ dBm}$					
f = 1278 MHz (L6 band) 6 12 - f = 1176 MHz (L5 band) 7 12 - RF OUT return loss RLo f = 1227 MHz (L2 band) 7 15 - dB			f = 1176 MHz (L5 band)	4	15	-		
RF OUT return loss RLo $f = 1176$ MHz (L5 band) 7 12 - $f = 1227$ MHz (L2 band) 7 15 - dB	RF IN return loss	RLi	f = 1227 MHz (L2 band)	5	15	-	dB	
RF OUT return loss RLo $f = 1176$ MHz (L5 band) 7 12 - $f = 1227$ MHz (L2 band) 7 15 - dB			f = 1278 MHz (L6 band)	6	12	-		
RF OUT return loss RLo f = 1227 MHz (L2 band) 7 15 - dB				_	4.0			
			t = 1176 MHz (L5 band)	(12	-		
	RF OUT return loss	RLo	f = 1227 MHz (L2 band)	7	15	-	dB	
f = 1278 MHz (L6 band) 7 17 -			f = 1278 MHz (L6 band)	7	17	-	1	



Automotive NJG1187AKGC-A

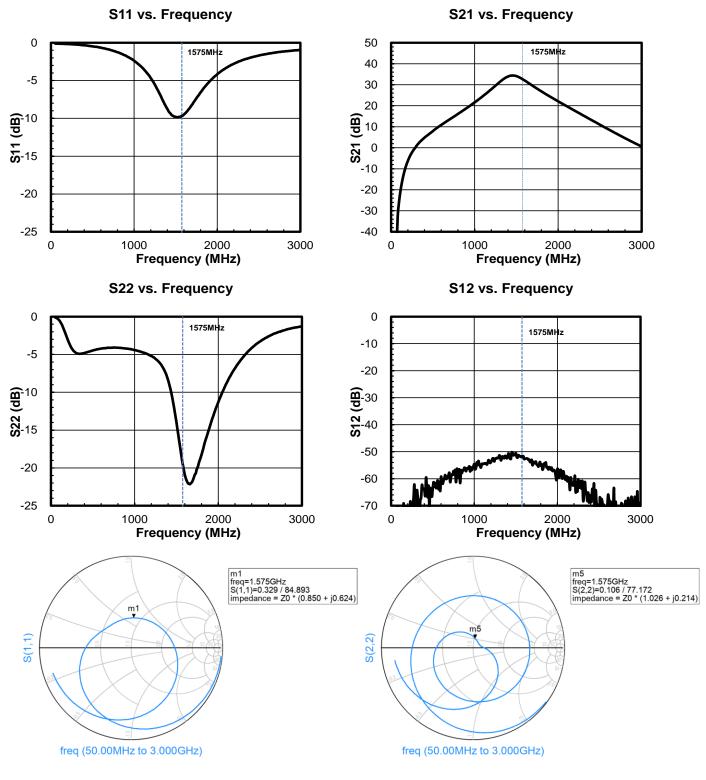
■ TYPICAL CHARACTERISTICS (L1 band application)





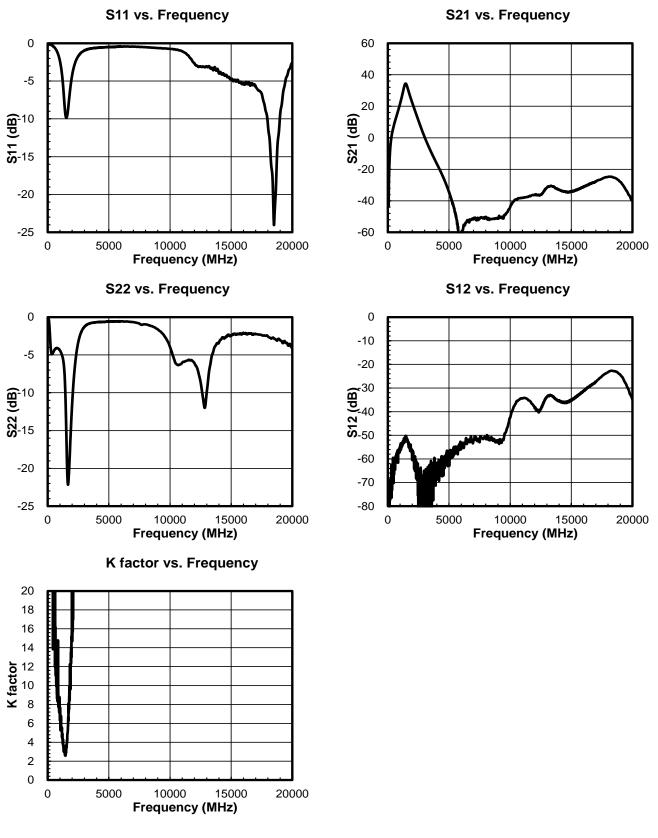
Automotive NJG1187AKGC-A

■ TYPICAL CHARACTERISTICS (L1 band application)





■ TYPICAL CHARACTERISTICS (L1 band application)



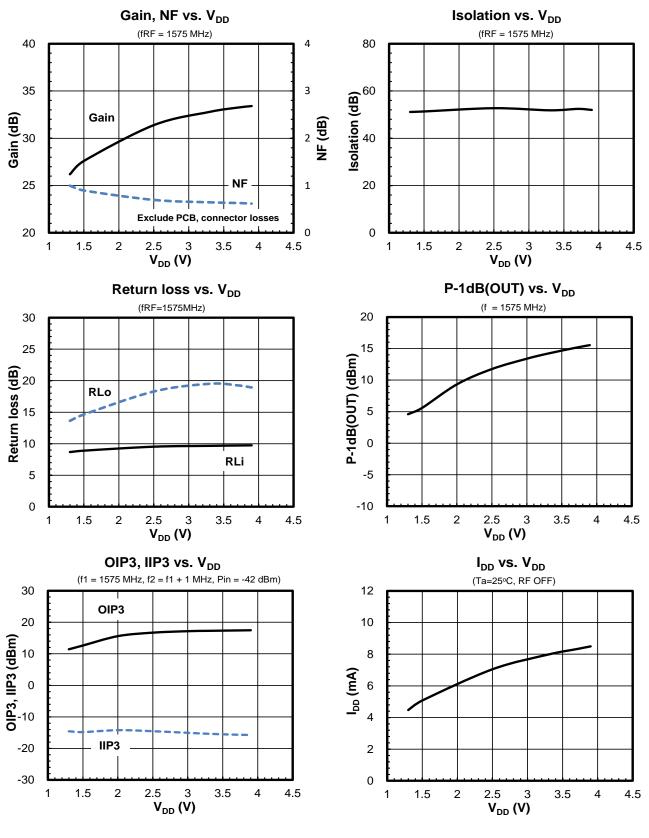


Automotive NJG1187AKGC-A

TYPICAL CHARACTERISTICS (L1 band application)

Conditions: $T_a = 25^{\circ}C$, $Z_s = Z_l = 50 \Omega$, with application circuit

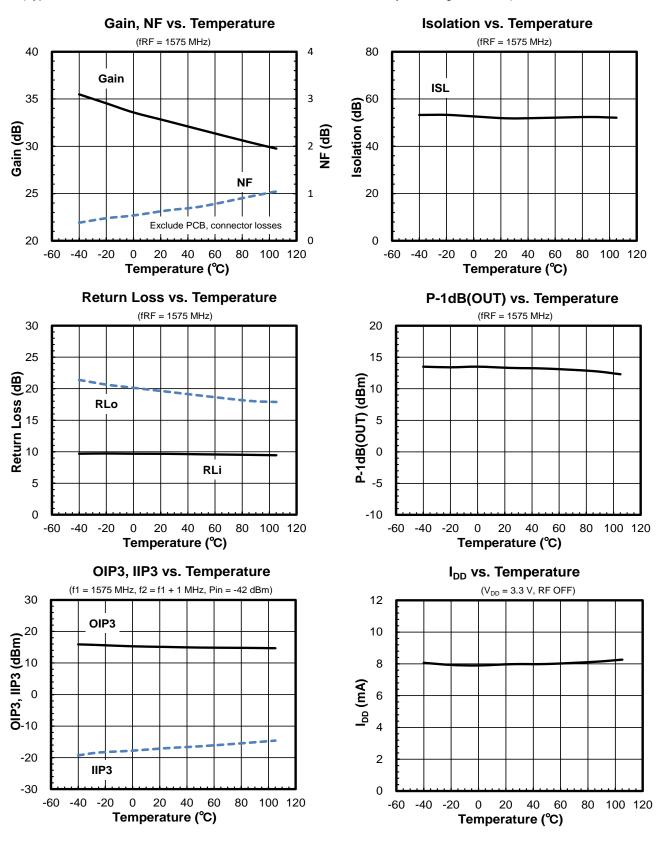
(Typical Characteristics are intended to be used as reference data; they are not guaranteed.)





TYPICAL CHARACTERISTICS (L1 band application)

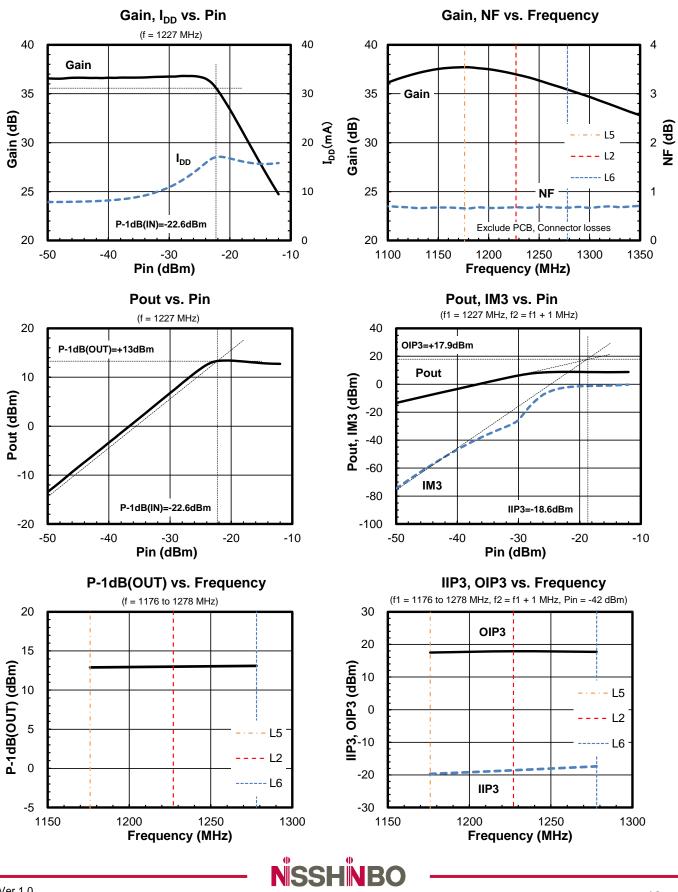
Conditions: $V_{DD} = 3.3 \text{ V}$, $Z_s = Z_l = 50 \Omega$, with application circuit (Typical Characteristics are intended to be used as reference data; they are not guaranteed.)



NSSHNBO

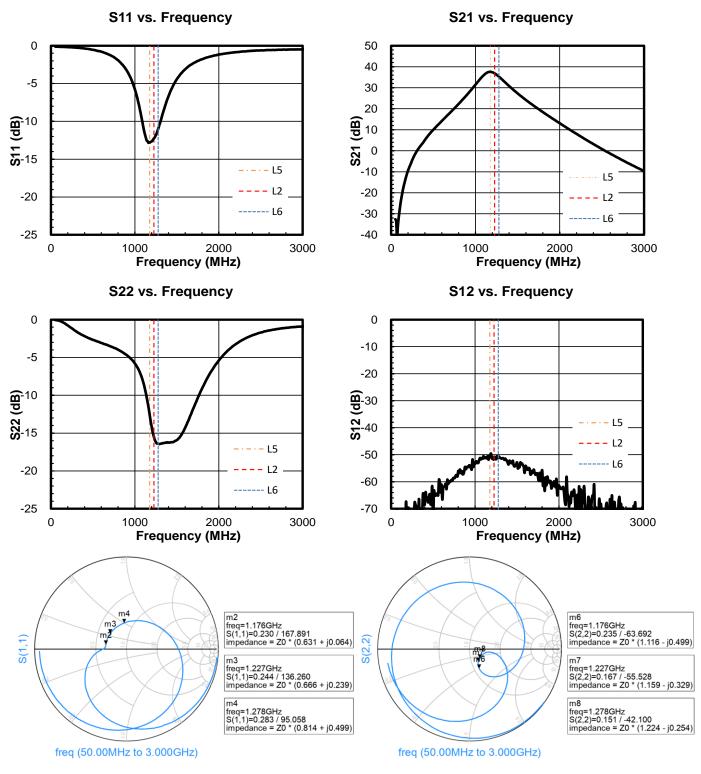
Automotive NJG1187AKGC-A

■ TYPICAL CHARACTERISTICS (L2/5/6 band application)



Automotive NJG1187AKGC-A

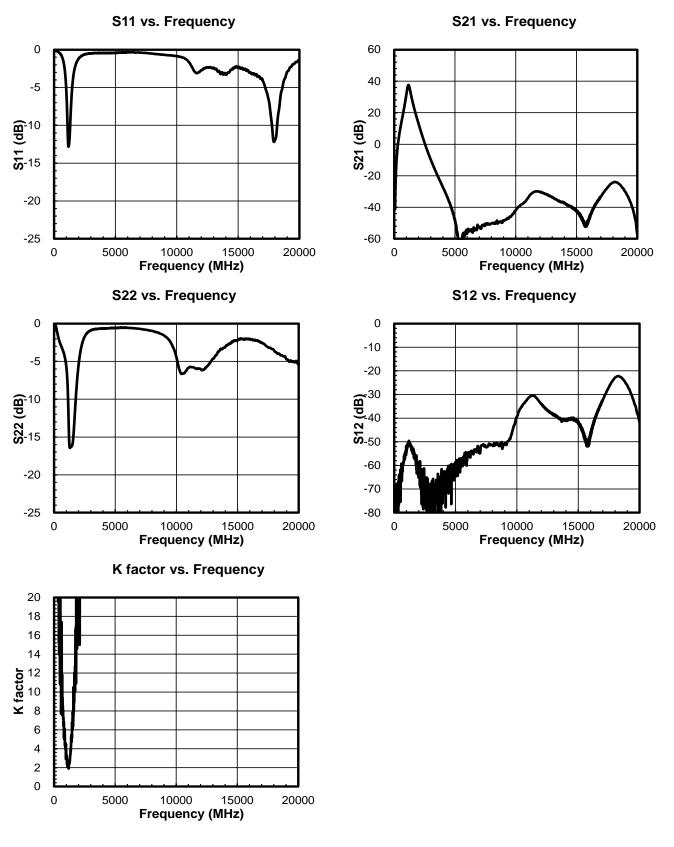
■ TYPICAL CHARACTERISTICS (L2/5/6 band application)





■ TYPICAL CHARACTERISTICS (L2/5/6 band application)

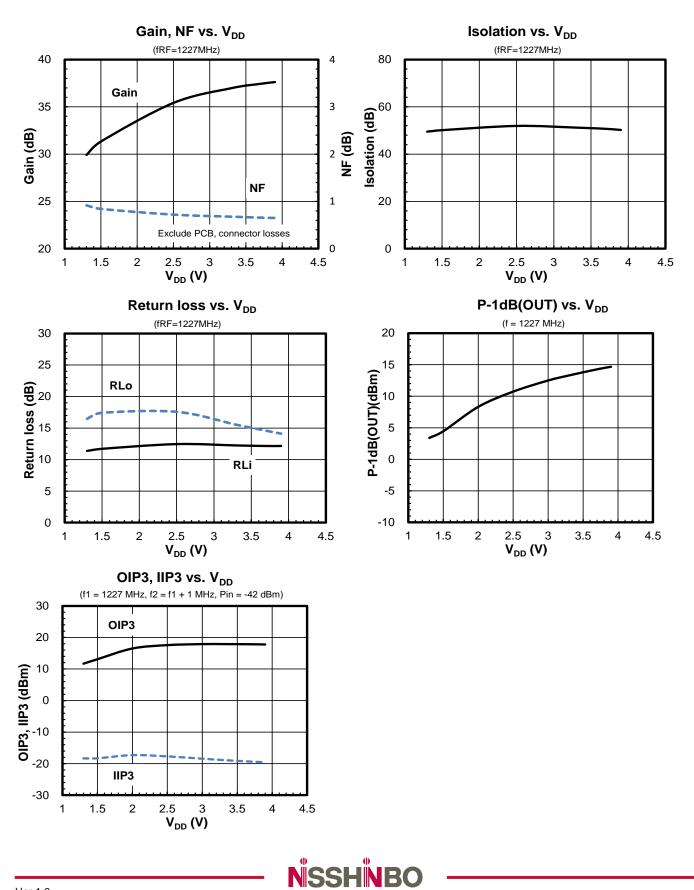
Conditions: $V_{DD} = 3.3 \text{ V}$, $T_a = 25^{\circ}\text{C}$, $Z_s = Z_l = 50 \Omega$, with application circuit (Typical Characteristics are intended to be used as reference data; they are not guaranteed.)



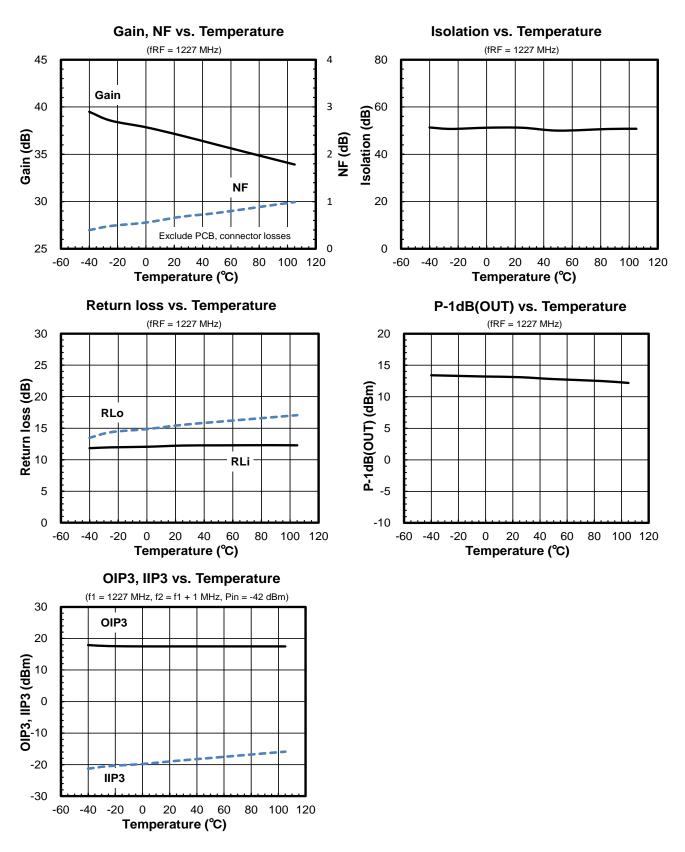
NSSHNBO



■ TYPICAL CHARACTERISTICS (L2/5/6 band application)



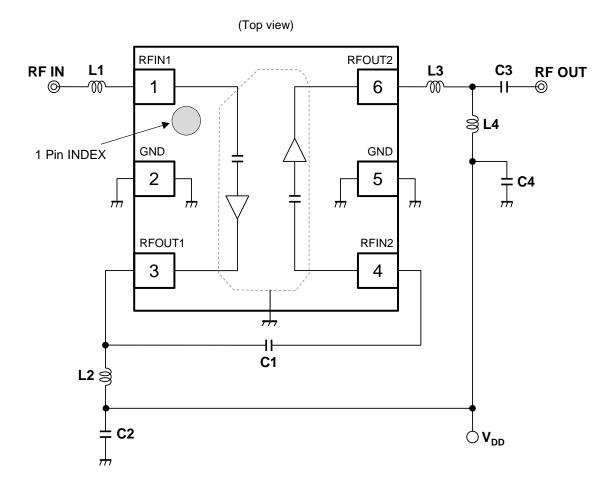
■ TYPICAL CHARACTERISTICS (L2/5/6 band application)





Automotive NJG1187AKGC-A

APPLICATION CIRCUIT





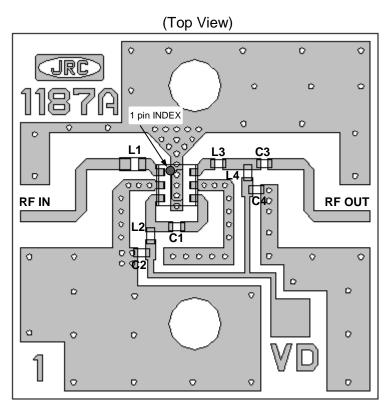
<PARTS LIST>

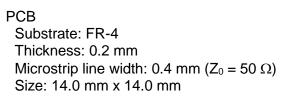
	Value		
Part ID	1559 to 1610 MHz (L1 band)	1164 to 1300 MHz (L2/5/6 band)	Notes
L1	10 nH	16 nH	LQW15AN_00 Series (MURATA)
L2	4.7 nH	8.2 nH	
L3	7.5 nH	9.1 nH	LQP03TN_02 Series (MURATA)
L4	27 nH	12 nH	
C1	3.3 pF	2.2 pF	
C2	4700 pF	4700 pF	GRM03 Series (MURATA)
C3	18 pF	18 pF	GILINOS GENES (MORATA)
C4	4700 pF	4700 pF	



APPLICATION NOTES

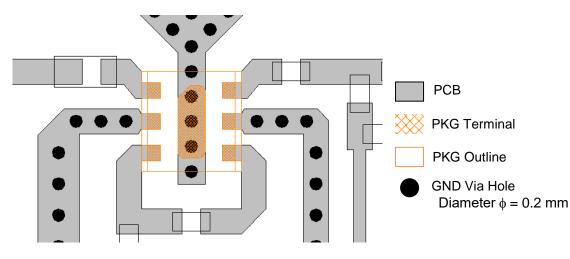
• EVALUATION BOARD





Automotive NJG1187AKGC-A

<PCB LAYOUT GUIDELINE>



PRECAUTIONS

• All external parts should be placed as close as possible to the LNA.

• For good RF performance, all GND terminals must be connected to PCB ground plane of substrate, and via-holes for GND should be placed near the LNA.



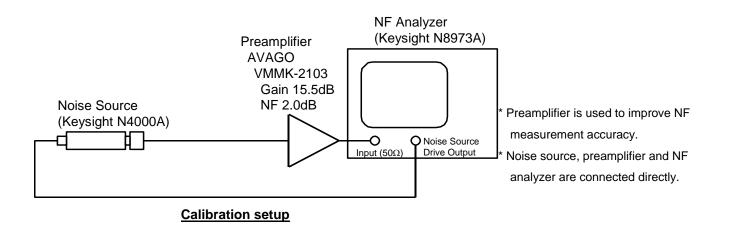
• NF MEASUREMENT BLOCK DIAGRAM

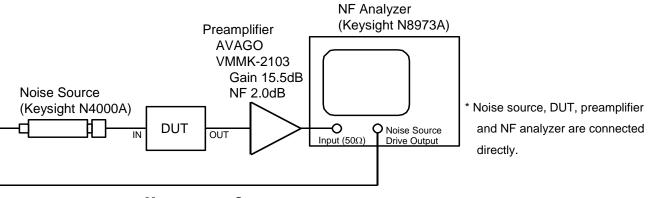
Measuring instruments

NF Analyzer	: Keysight N8973A
Noise Source	: Keysight N4000A

Setting the NF analyzer

Measurement mode form	
Device under test	: Amplifier
System downconverter	: off
Mode setup form	
Sideband	: LSB
Averages	: 8
Average mode	: Point
Bandwidth	: 4 MHz
Loss comp	: off
Tcold	: setting the temperature of noise source (Auto)





Measurement Setup



• REVISION HISTORY

Date	Revision	Changes
19.Apri.2023	Ver.1.0	Initial

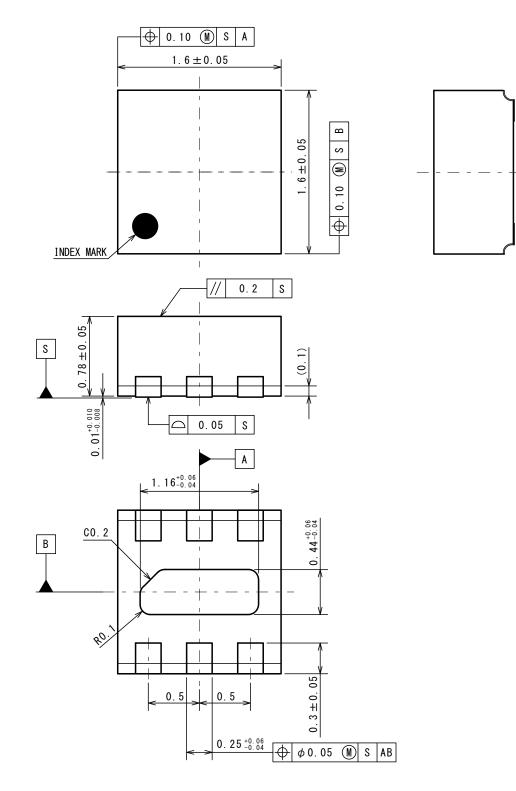


DFN6-GC(ESON6-GC)

PACKAGE DIMENSIONS

PI-DFN6-GC-E-B

UNIT: mm



PI-DFN6-GC-E-B

Nisshinbo Micro Devices Inc.

DFN6-GC(ESON6-GC)

■ EXAMPLE OF SOLDER PADS DIMENSIONS

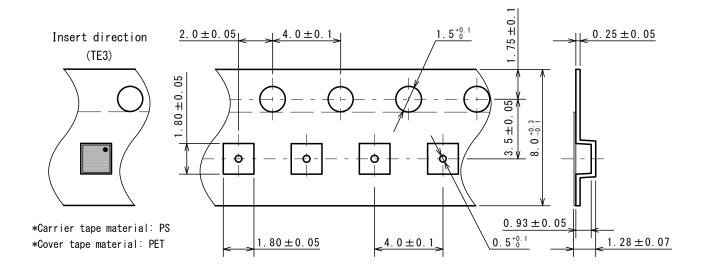
UNIT: mm 1.26 1.16 0.9 P0.0 :Land :Mask(Open area) 0.4 Metal mask thickness:100 μ m 0.5 2.4 2.3 :Resist(Open area) 75 65 :Package outline 0. o. R0.07 0.5

NISSHINBO

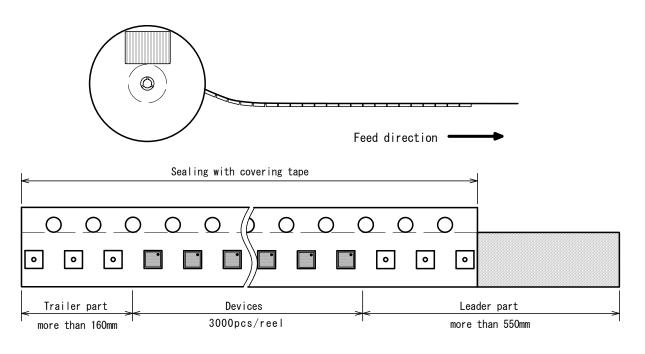
DFN6-GC(ESON6-GC)

PACKING SPEC

(1) Taping dimensions / Insert direction



(2) Taping state



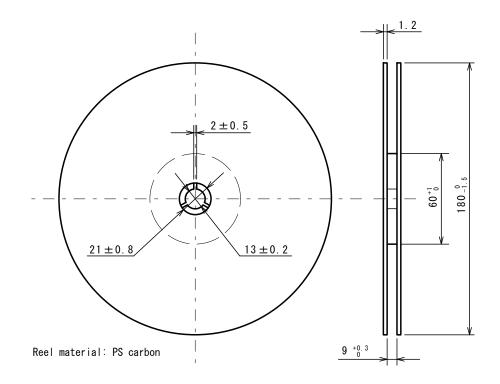
PI-DFN6-GC-E-B

UNIT: mm

DFN6-GC(ESON6-GC)

PI-DFN6-GC-E-B

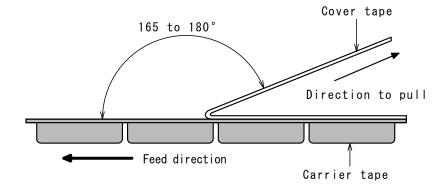
(3) Reel dimensions



(4) Peeling strength

Peeling strength of cover tape

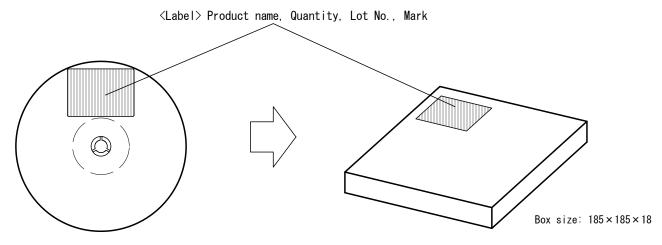
Peeling angle 165 to 180° degrees to the taped surface.
Peeling speed 300mm/min
Peeling strength 0.1 to 1.0N



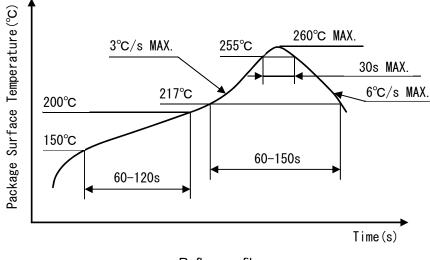


PI-DFN6-GC-E-B

(5) Packing state



HEAT-RESISTANCE PROFILES



Reflow profile

- 1. The products and the product specifications described in this document are subject to change or discontinuation of production without notice for reasons such as improvement. Therefore, before deciding to use the products, please refer to our sales representatives for the latest information thereon.
- 2. The materials in this document may not be copied or otherwise reproduced in whole or in part without the prior written consent of us.
- 3. This product and any technical information relating thereto are subject to complementary export controls (so-called KNOW controls) under the Foreign Exchange and Foreign Trade Law, and related politics ministerial ordinance of the law. (Note that the complementary export controls are inapplicable to any application-specific products, except rockets and pilotless aircraft, that are insusceptible to design or program changes.) Accordingly, when exporting or carrying abroad this product, follow the Foreign Exchange and Foreign Trade Control Law and its related regulations with respect to the complementary export controls.
- 4. The technical information described in this document shows typical characteristics and example application circuits for the products. The release of such information is not to be construed as a warranty of or a grant of license under our or any third party's intellectual property rights or any other rights.
- 5. The products listed in this document are intended and designed for automotive applications. Those customers intending to use a product in an application requiring extreme quality and reliability, for example, in a highly specific application where the failure or misoperation of the product could result in human injury or death should first contact us.
 - Aerospace Equipment
 - Equipment Used in the Deep Sea
 - Power Generator Control Equipment (nuclear, steam, hydraulic, etc.)
 - Life Maintenance Medical Equipment
 - Fire Alarms / Intruder Detectors
 - Vehicle Control Equipment (airplane, railroad, ship, etc.)
 - Various Safety Devices
 - Traffic control system
 - Combustion equipment

In case your company desires to use this product for any applications other than general electronic equipment mentioned above, make sure to contact our company in advance. Note that the important requirements mentioned in this section are not applicable to cases where operation requirements such as application conditions are confirmed by our company in writing after consultation with your company.

- 6. We are making our continuous effort to improve the quality and reliability of our products, but semiconductor products are likely to fail with certain probability. In order to prevent any injury to persons or damages to property resulting from such failure, customers should be careful enough to incorporate safety measures in their design, such as redundancy feature, fire containment feature and fail-safe feature. We do not assume any liability or responsibility for any loss or damage arising from misuse or inappropriate use of the products.
- 7. The products have been designed and tested to function within controlled environmental conditions. Do not use products under conditions that deviate from methods or applications specified in this datasheet. Failure to employ the products in the proper applications can lead to deterioration, destruction or failure of the products. We shall not be responsible for any bodily injury, fires or accident, property damage or any consequential damages resulting from misuse or misapplication of the products.
- 8. Quality Warranty
 - 8-1. Quality Warranty Period

In the case of a product purchased through an authorized distributor or directly from us, the warranty period for this product shall be one (1) year after delivery to your company. For defective products that occurred during this period, we will take the quality warranty measures described in section 8-2. However, if there is an agreement on the warranty period in the basic transaction agreement, quality assurance agreement, delivery specifications, etc., it shall be followed.

8-2. Quality Warranty Remedies

When it has been proved defective due to manufacturing factors as a result of defect analysis by us, we will either deliver a substitute for the defective product or refund the purchase price of the defective product.

Note that such delivery or refund is sole and exclusive remedies to your company for the defective product.

- 8-3. Remedies after Quality Warranty Period With respect to any defect of this product found after the quality warranty period, the defect will be analyzed by us. On the basis of the defect analysis results, the scope and amounts of damage shall be determined by mutual agreement of both parties. Then we will deal with upper limit in Section 8-2. This provision is not intended to limit any legal rights of your company.
- 9. Anti-radiation design is not implemented in the products described in this document.
- 10. The X-ray exposure can influence functions and characteristics of the products. Confirm the product functions and characteristics in the evaluation stage.
- 11. WLCSP products should be used in light shielded environments. The light exposure can influence functions and characteristics of the products under operation or storage.
- 12. Warning for handling Gallium and Arsenic (GaAs) products (Applying to GaAs MMIC, Photo Reflector). These products use Gallium (Ga) and Arsenic (As) which are specified as poisonous chemicals by law. For the prevention of a hazard, do not burn, destroy, or process chemically to make them as gas or power. When the product is disposed of, please follow the related regulation and do not mix this with general industrial waste or household waste.
- 13. Please contact our sales representatives should you have any questions or comments concerning the products or the technical information.



Nisshinbo Micro Devices Inc.

Official website https://www.nisshinbo-microdevices.co.jp/en/

Purchase information

https://www.nisshinbo-microdevices.co.jp/en/buy/